SiC08A065T

SILICON CARBIDE SCHOTTKY DIODE

Voltage	650 V	Current	8 A

Features

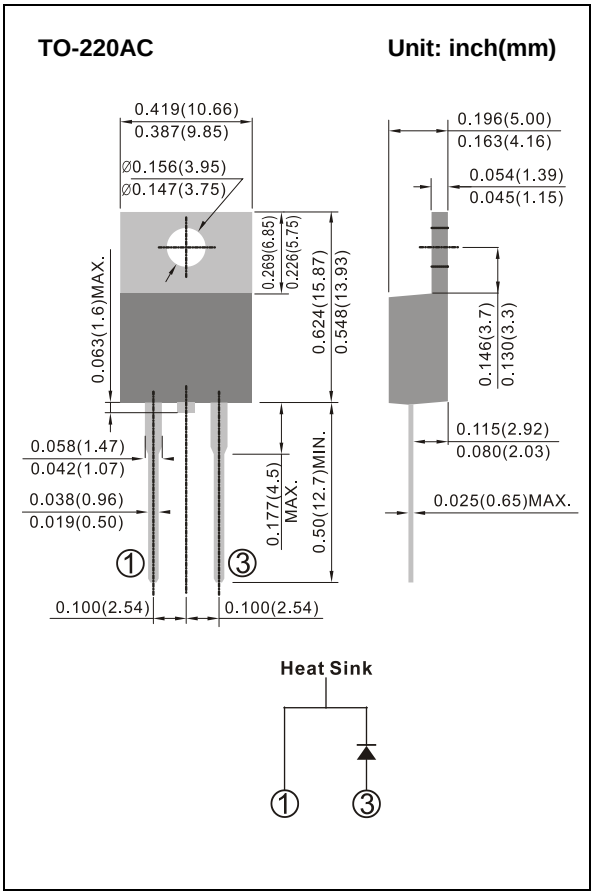
- Temperature Independent Switching Behavior
- Low Conduction and Switching Loss
- High Surge Current Capability
- Positive Temperature Coefficient on V_F
- Fast Reverse Recovery

Mechanical Data

- Case: Molded plastic, TO-220AC
- Marking: 08A065T

Benefits

- High Frequency Operation
- Higher System Efficiency
- Environmental Protection
- Parallel Device Convenience
- Hard Switching & High Reliability
- High Temperature Application



Maximum Ratings

PARAMETER	SYMBOL	TEST CONDITIONS	VALUE	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	T_J=25°C	650	V
Maximum RMS Voltage	V_{RSM}	T_J=25°C	650	V
Maximum DC Blocking Voltage	V_R	T_J=25°C	650	V
Continuous Forward Current	$I_{F(AV)}$	T_C=25°C	21	A
		T_C=125°C	10	A
		T_C=150°C	8	A
Repetitive Peak Forward Surge Current (T_P=10mS, Half Sine Wave, D=0.1)	I_{FRM}	T_C=25°C	47	A
		T_C=125°C	39	A

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Maximum Ratings

PARAMETER	SYMBOL	TEST CONDITIONS	VALUE	UNITS
Non-Repetitive Peak Forward Surge Current (T_P=10mS, Half Sine Wave)	I_{FSM}	T_C=25°C	62	A
		T_C=125°C	54	A
Non-Repetitive Peak Forward Surge Current (T_P=10uS, Pulse)		T_C=25°C	250	A
Power Dissipation	P_D	T_C=25°C	100	W
		T_C=125°C	33	W
Operating Junction Temperature	T_J		175	°C
Storage Temperature	T_{STG}		-55 to 175	°C
Thermal Resistance Junction to Case	$R_{\theta JC}$		1.5	°C/W

Electrical Characteristics

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
DC Blacking Voltage	V_{DC}	I_R =100uA, T_J=25°C	650	770	-	V
Forward Voltage	V_F	I_F =8A, T_J=25°C	-	1.5	1.8	V
		I_F =8A, T_J=175°C	-	1.9	2.2	V
Reverse Current	I_R	V_R =650V, T_J=25°C	-	3	60	uA
		V_R =650V, T_J=175°C	-	20	190	uA
Total Capacitive Charge	Q_C	I_F =8A, di/dt=300A/uS, V_R =400V, T_J=25°C	-	15.5	-	nC
Total Capacitance	C	V_R =1V, T_J=25°C, f=1MHz	-	306	-	pF
		V_R =200V, T_J=25°C, f=1MHz	-	47	-	pF
		V_R =400V, T_J=25°C, f=1MHz	-	47	-	pF

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TYPICAL CHARACTERISTIC CURVES

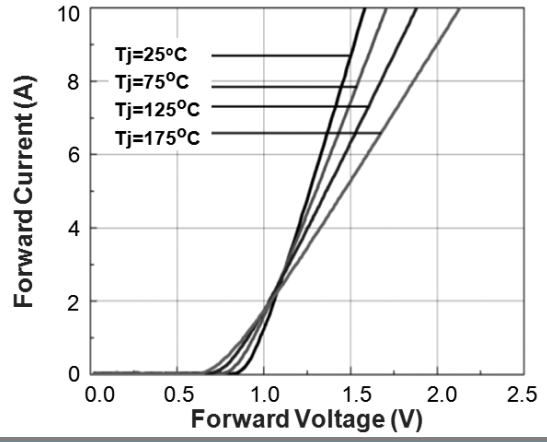

Fig.1 Forward Characteristics

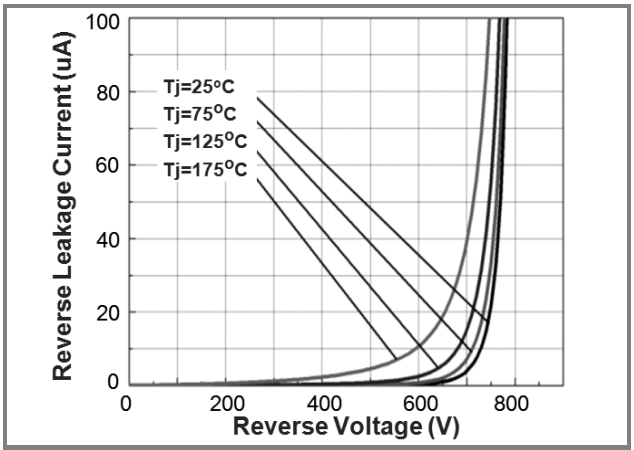

Fig.2 Reverse Characteristics

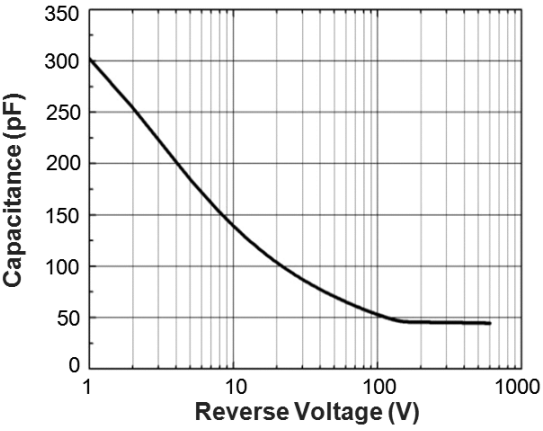

Fig.3 Capacitance vs. Reverse Voltage

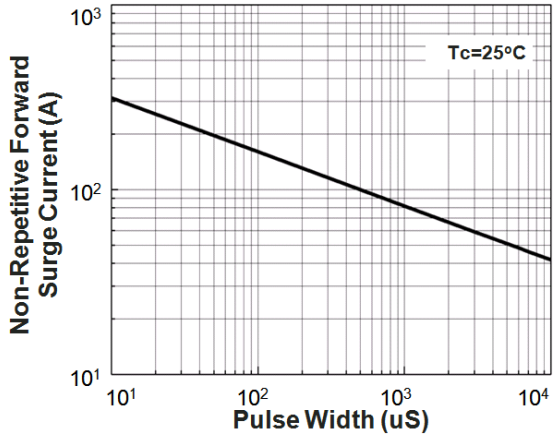

Fig.4 Non-Repetitive Peak Forward Surge Current
(Pulse Mode)

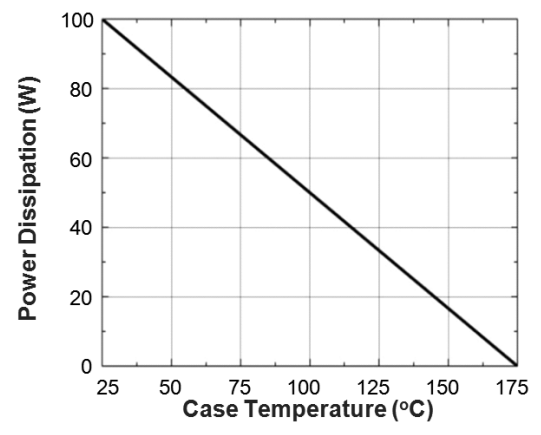

Fig.5 Power Derating

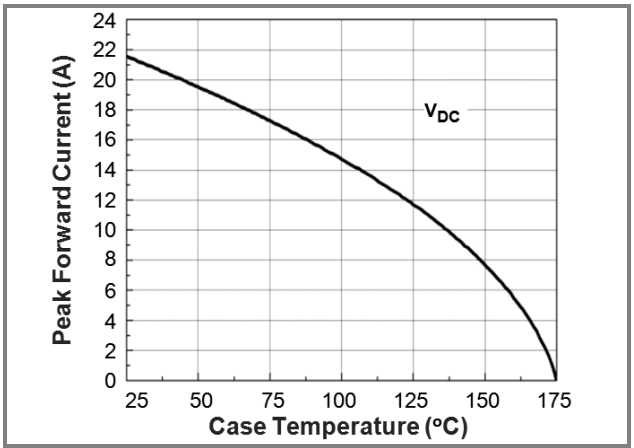

Fig.6 Current Derating

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Part No Packing Code Version

Part No Packing Code	Package Type	Packing type	Marking	Version
SIC08A065T_T0_00001	TO-220AC	50pcs / Tube	08A065T	Halogen free

SiC08A065T

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